# **Infrared detector PbS photoconductive detector Bondable bare chip**



#### **Features**

- Bondable electrodes for COB mounting
- Very high sensitivity
- High durability for rugged operation

## **Applications**

- Gas analysis
- Spectroscopy
- Process control
- Temperature control

## **Specification**

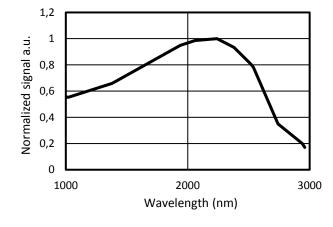
Type No.	Package	Active area	Operating	Storage temperature [°C]		
		[mm x mm]	temperature [°C]			
PbS030030BC	Bare chip / thin film encapsulation	3 x 3	-30 to +70	-55 to +70		

## **Electrical and optical characteristics**

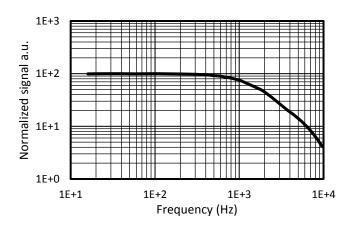
Type No.	Element	Peak wave-	20%	Peak		Peak D*		Time	Dark
	temperat	length λ <sub>P</sub>	cut-off	responsivity		(606 Hz, 1 Hz)		constant	resistance
	ure	[µm]	wavelength	S [V/W]		[cm·Hz½/W]		[µs]	$R_D [M\Omega]$
	[°C]		λ <sub>c</sub> [μm]	Тур.	Min.	Тур.	Min.	Тур.	
PbS030030BC	26	2.2	2.9	3 · 10 <sup>5</sup>	1 · 10 <sup>5</sup>	1 · 10 <sup>11</sup>	5 · 10 <sup>10</sup>	200	0.3 – 3

- Measured with 1550 nm LED, incident power 22 μW/cm<sup>2</sup>
- Measured in a voltage divider circuit with 10 V/mm and linearly extrapolated to 50 V/mm
- Photo responsivity and detectivity are measured with matched load resistance (R<sub>L</sub> = R<sub>D</sub>)
- Without filter or window

## **Typical spectral response**



# **Typical frequency response**



T +49 (0) 621 60 567 39

F +49 (0) 621 60 956 91 W www.hertzstueck.de

E info@hertzstueck.de

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#### **Storage**

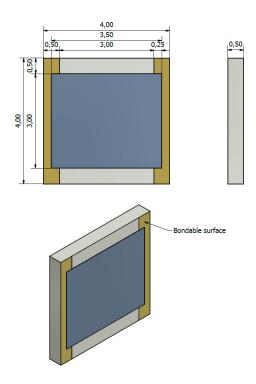
- Storage temperature: -55°C to 70°C
- Exposure to UV light results in permanent damage
- Prolonged exposure to visible light results in low dark resistance

## **Handling**

- Active area is scratch sensitive, protect top surface from any mechanical contact
- Ensure dust-free environment for device handling

## Mechanical outline (dimensions in mm)

#### PbS030030BC



#### Die attach

- Use clean, soft rubber tip for pick-and place handling
- UV-curing is not suitable due to permanent damage by UV light exposure
- Element temperature should never exceed 70°C

# Wire bonding

- Electrodes are optimized for room temperature Al-wire bonding
- Element temperature should never exceed 70°C

#### trinamiX GmbH